

CL 10/24/05

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
		("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 16:59
S1	128	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:35
S2	271	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:35
S3	224	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:35
S4	1323	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:36
S5	115	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:36
S6	96	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:38
S7	250	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:38
S8	670	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:38

S9	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 15:38
S10	390	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:01
S11	52	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:01
S12	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:00
S13	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:00
S14	137	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:00
S15	137	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:00
S16	128	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S17	271	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S18	224	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02

S19	1323	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S20	115	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S21	96	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S22	250	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S23	670	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S24	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:02
S25	480	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:03
S26	332	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:03
S27	0	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:03
S28	94	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00

S29	81	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:07
S30	0	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:08
S31	7	(S16 or S17 or S18 or S19 or S20 or S21 or S22 or S23 or S24) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:08
S32	128	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S33	271	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S34	224	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S35	1323	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S36	115	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S37	96	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S38	250	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24

S39	670	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S40	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S41	480	(S32 or S33 or S34 or S35 or S36 or S37 or S38 or S39 or S40) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S42	0	(S32 or S33 or S34 or S35 or S36 or S37 or S38 or S39 or S40) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S43	0	(S32 or S33 or S34 or S35 or S36 or S37 or S38 or S39 or S40) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S44	0	(S32 or S33 or S34 or S35 or S36 or S37 or S38 or S39 or S40) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:24
S45	10	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:30
S46	13	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:30
S47	3	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/01 17:31
S48	128	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00

S49	271	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S50	224	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S51	1323	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S52	115	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S53	96	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S54	250	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S55	670	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S56	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:00
S57	0	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:01
S58	0	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:03

S59	2	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:03
S60	1286	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:03
S61	2	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:13
S62	0	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:14
S63	0	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:14
S64	332	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:14
S65	146	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 09:56
S66	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/02/02 07:38
S67	121	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:43
S68	60	(S48 or S49 or S50 or S51 or S52 or S53 or S54 or S55 or S56) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 07:43

S69	15	("4187116").URPN.	USPAT	OR	OFF	2005/02/02 07:57
S70	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 09:58
S71	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 09:59
S72	9	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/02/02 09:59
S73	133	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S74	278	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S75	232	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S76	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S77	123	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S78	102	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S79	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S80	674	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S81	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S82	451	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S83	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S84	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S85	158	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S86	158	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S87	57	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S88	133	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S89	278	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S90	232	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S91	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S92	123	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S93	102	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S94	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S95	674	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S96	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S97	488	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S98	339	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S99	0	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S10 0	96	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 1	83	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 2	0	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 3	7	(S88 or S89 or S90 or S91 or S92 or S93 or S94 or S95 or S96) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 4	133	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 5	278	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 6	232	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 7	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 8	123	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S10 9	102	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S11 0	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 1	674	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 2	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 3	488	(S104 or S105 or S106 or S107 or S108 or S109 or S110 or S111 or S112) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 4	0	(S104 or S105 or S106 or S107 or S108 or S109 or S110 or S111 or S112) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 5	0	(S104 or S105 or S106 or S107 or S108 or S109 or S110 or S111 or S112) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 6	0	(S104 or S105 or S106 or S107 or S108 or S109 or S110 or S111 or S112) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 7	10	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 8	17	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S11 9	3	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S12 0	133	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 1	278	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 2	232	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 3	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 4	123	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 5	102	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 6	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 7	674	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 8	287	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S12 9	0	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and(electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S13 0	0	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 1	5	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 2	1322	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 3	3	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 4	0	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 5	0	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 6	339	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 7	149	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S13 8	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/08/10 13:29
S13 9	125	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29

S14 0	62	(S120 or S121 or S122 or S123 or S124 or S125 or S126 or S127 or S128) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S14 1	15	("4187116").URPN.	USPAT	OR	OFF	2005/08/10 13:29
S14 2	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S14 3	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S14 4	13	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/08/10 13:29
S14 5	12	("5039632" "5386006" "5424126" "6025454" "6242626" "6478994")".PN"	USPAT	OR	OFF	2005/08/11 09:52
S14 6	7	"5884134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 09:53
S14 7	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 09:55
S14 8	3	"5684134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 09:55
S14 9	1	"56084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 09:56
S15 0	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 09:57

S15 1	2	"58084184"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 09:58
S15 2	1	"60145910"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 10:41
S15 3	8	"6422041"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/08/11 10:41
S15 4	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S15 5	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S15 6	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S15 7	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S15 8	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S15 9	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 0	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S16 1	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 2	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 3	479	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 4	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 5	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 6	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 7	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 8	59	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S16 9	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 0	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S17 1	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 2	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 3	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 4	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 5	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 6	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 7	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 8	490	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S17 9	341	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 0	0	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S18 1	97	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 2	84	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 3	0	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 4	8	(S169 or S170 or S171 or S172 or S173 or S174 or S175 or S176 or S177) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 5	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 6	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 7	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 8	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S18 9	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 0	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S19 1	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 2	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 3	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 4	490	(S185 or S186 or S187 or S188 or S189 or S190 or S191 or S192 or S193) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 5	1	(S185 or S186 or S187 or S188 or S189 or S190 or S191 or S192 or S193) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 6	1	(S185 or S186 or S187 or S188 or S189 or S190 or S191 or S192 or S193) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 7	1	(S185 or S186 or S187 or S188 or S189 or S190 or S191 or S192 or S193) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 8	12	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S19 9	20	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 0	5	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S20 1	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 2	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 3	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 4	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 5	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 6	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 7	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 8	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S20 9	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 0	1	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S21 1	1	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 2	6	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 3	1333	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 4	4	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 5	0	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 6	1	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 7	341	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 8	150	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S21 9	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/24 15:44
S22 0	126	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S22 1	63	(S201 or S202 or S203 or S204 or S205 or S206 or S207 or S208 or S209) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 2	15	("4187116").URPN.	USPAT	OR	OFF	2005/10/24 15:44
S22 3	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 4	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 5	14	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 6	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 7	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 8	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S22 9	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 0	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S23 1	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 2	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 3	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 4	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 5	479	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 6	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 7	0	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and EFAS	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 8	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and electric adj field	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S23 9	169	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and (electric adj field)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S24 0	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44

S24 1	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:44
S24 2	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 3	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 4	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 5	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 6	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 7	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 8	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S24 9	490	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and (silicon adj nitride) and (silicon adj carbide)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 0	341	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45

S25 1	0	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 2	84	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and ((silicon adj nitride) same (silicon adj carbide)) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 3	0	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field same assisted same sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 4	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 5	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 6	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 7	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 8	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S25 9	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 0	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45

S26 1	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 2	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 3	490	(S254 or S255 or S256 or S257 or S258 or S259 or S260 or S261 or S262) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 4	1	(S254 or S255 or S256 or S257 or S258 or S259 or S260 or S261 or S262) and (silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 5	1	(S254 or S255 or S256 or S257 or S258 or S259 or S260 or S261 or S262) and (silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 6	1	(S254 or S255 or S256 or S257 or S258 or S259 or S260 or S261 or S262) and (silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 7	135	264/405.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 8	280	264/430.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S26 9	235	264/434.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 0.	1326	264/332.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45

S27 1	127	264/682.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 2	103	264/683.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 3	254	501/91.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 4	680	501/92.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 5	288	501/93.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 6	1	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 7	1	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 8	1333	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (spark plasma sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S27 9	0	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and (plasma adj activated adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 0	1	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and (field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45

S28 1	126	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 2	59	("I1" or "I2" or "I3" or "I4" or "I5" or "I6" or "I7" or "I8" or "I9") and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 3	97	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and (silicon adj nitride) and (silicon adj carbide) and sintering and electric	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 4	8	(S240 or S241 or S242 or S243 or S244 or S245 or S246 or S247 or S248) and ((silicon adj nitride) same (silicon adj carbide)) and (electric same field) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 5	12	(silicon adj nitride) and (silicon adj carbide) and mukherjee.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 6	20	(silicon adj nitride) and (silicon adj carbide) and wan.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:17
S28 7	5	(silicon adj nitride) and (silicon adj carbide) and gasch.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 8	6	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (electric adj field adj assisted adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S28 9	4	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and (spark adj plasma adj sintering)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 0	9	("5352641" "5468697" "5525556" "5616527" "5643843" "5648028" "5767025" "5902761" "5912200").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/24 15:45

S29 1	63	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering and ((sintering adj aid) or (densification adj aid))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 2	15	("4187116").URPN.	USPAT	OR	OFF	2005/10/24 15:45
S29 3	7	"02160669"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 4	11	"6254940"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 5	14	"6420293"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 6	150	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride).clm. and (silicon adj carbide).clm. and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 7	341	(S267 or S268 or S269 or S270 or S271 or S272 or S273 or S274 or S275) and (silicon adj nitride) and (silicon adj carbide) and sintering	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 15:45
S29 8	12	("5039632" "5386006" "5424126" "6025454" "6242626" "6478994").PN"	USPAT	OR	OFF	2005/10/24 15:45
S29 9	7	"5884134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 0	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 1	3	"5684134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45

S30 2	1	"56084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 3	1	"58084134"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 4	2	"58084184"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 5	1	"60145910"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 6	8	"6422041"	USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/10/24 15:45
S30 7	22	("4097293" "4141740" "4146379" "4158687" "4341533" "4502983" "4569922" "4581295").PN. OR ("4829027").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/24 16:00
S30 8	18	("4097293" "4141740" "4146379" "4158687" "4341533" "4502983" "4569922" "4581295").PN. OR ("4829027").URPN. and alumina	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/24 16:00
S30 9	8	("4097293" "4141740" "4146379" "4158687" "4341533" "4502983" "4569922" "4581295").PN. OR ("4829027").URPN. and alumina and (alumina adj nitride)	US-PGPUB; USPAT; USOCR	OR	OFF	2005/10/24 16:00
S31 0	33	"4184882"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:18
S31 1	23	"4800182"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:27

S31 2	11	"5376599"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:28
S31 3	11	"5523267"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:30
S31 4	5	"5541143"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:31
S31 5	14	"5134097"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:31
S31 6	23	"4800182"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:32
S31 7	33	"4184882"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:38
S31 8	717	264/123.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:38
S31 9	9	264/123.ccls. and (silicon) and nitride and carbide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:40
S32 0	104	264/125.ccls. and (silicon) and nitride and carbide	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2005/10/24 17:40